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SEMICONDUCTOR PHYSICS

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M. Ashry and S. Fares
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Wang Wei, Wang Jing, Zhao Mei, Liang Renrong, and Xu Jun

SEMICONDUCTOR MATERIALS

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Zhang Dongyan, Zheng Xinhe, Li Xuefei, Wu Yuanyuan, Wang Jianfeng, and Yang Hui
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Wang Xinjian, Song Hang, Li Zhiming, Jiang Hong, Li Dabing, Miao Guoqing, Chen Yiren, and Sun Xiaojuan

SEMICONDUCTOR DEVICES

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Wen Rumeng, Sun Hao, Teng Teng, Li Lingyun, and Sun Xiaowei
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Li Panpan, Li Hongjian, Zhang Yiyun, Li Zhicong, Liang Meng, Li Jing, and Wang Guohong
- 104003 High voltage SOI LDMOS with a compound buried layer (5 pages)**
Luo Xiaorong, Hu Gangyi, Zhou Kun, Jiang Yongheng, Wang Pei, Wang Qi, Luo Yinchun, Zhang Bo, and Li Zhaoji
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Hao Daoxin, Cheng Jia, Ji Linhong, and Sun Yuchun
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Du Chunhui, He Changde, Yu Jiaqi, Ge Xiaoyang, Zhang Yongping, and Zhang Wendong
- 104006 Contact size scaling of a W-contact phase-change memory cell based on numerical simulation (5 pages)**
Wei Yiqun, Lin Xinnan, Jia Yuchao, Cui Xiaole, Zhang Xing, and Song Zhitang
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Wang Yuhai, Qin Zhengkun, Wang Chunxu, and Wang Lizhong

(Continued on inside back cover)

SEMICONDUCTOR INTEGRATED CIRCUITS

- 105001** A low power 2.5–5 GHz low-noise amplifier using 0.5- μm GaAs pHEMT technology (4 pages)
Peng Yangyang, Lu Kejie, and Sui Wenquan
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Jiang Peichen, Guan Rui, Wang Wufeng, Chen Dongpo, and Zhou Jianjun
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Zhang Qiang, Ni Weining, Shi Yin, and Yu Yude
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Wang Xiaoyu, Yang Haigang, Li Fanyang, Yin Tao, and Liu Fei
- 105005** Design of low power common-gate low noise amplifier for 2.4 GHz wireless sensor network applications (7 pages)
Zhang Meng and Li Zhiquan
- 105006** A 7–27 GHz DSCL divide-by-2 frequency divider (5 pages)
Guo Ting, Li Zhiquan, Li Qin, and Wang Zhigong
- 105007** A single-event-hardened phase-locked loop using the radiation-hardened-by-design technique (6 pages)
Han Benguang, Guo Zhongjie, Wu Longsheng, and Liu Youbao
- 105008** A wideband LC-VCO with small VCO gain variation and adaptive power control (6 pages)
Li Bin, Fan Xiangning, and Wang Zhigong
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Chen Liang and Li Zhiquan
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Zhang Yiwen, Chen Chixiao, Yu Bei, Ye Fan, and Ren Junyan
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Li Yanming, Mao Xiangyu, Wen Changbao, and Wen Limin
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Zhao Huidong, Hei Yong, Qiao Shushan, and Ye Tianchun

SEMICONDUCTOR TECHNOLOGY

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Zhao Jianyi, Guo Jian, Huang Xiaodong, Zhou Ning, and Liu Wen
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Wang Zhihao, Liu Wen, Wang Lei, Zuo Qiang, and Zhao Yanli
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Su Jianxiu, Du Jiayi, Ma Lijie, Zhang Zhuqing, and Kang Renke